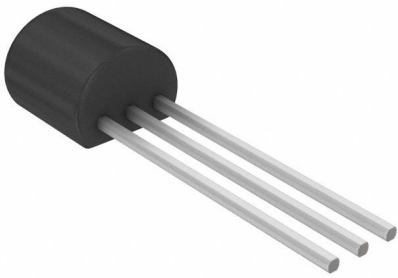


# 2SA11270RA Datasheet

[www.digi-electronics.com](http://www.digi-electronics.com)



<https://www.DiGi-Electronics.com>

DiGi Electronics Part Number	2SA11270RA-DG
Manufacturer	<a href="#">Panasonic Electronic Components</a>
Manufacturer Product Number	2SA11270RA
Description	TRANS PNP 55V 0.1A TO92-B1
Detailed Description	Bipolar (BJT) Transistor PNP 55 V 100 mA 200MHz 400 mW Through Hole TO-92-B1



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

2SA11270RA

Series:

-

Transistor Type:

PNP

Voltage - Collector Emitter Breakdown (Max):

55 V

Current - Collector Cutoff (Max):

1 $\mu$ A

Power - Max:

400 mW

Operating Temperature:

150°C (TJ)

Package / Case:

TO-226-3, TO-92-3 (TO-226AA) Formed Leads

Base Product Number:

2SA1127

Manufacturer:

Panasonic Electronic Components

Product Status:

Obsolete

Current - Collector (Ic) (Max):

100 mA

Vce Saturation (Max) @ Ib, Ic:

600mV @ 10mA, 100mA

DC Current Gain (hFE) (Min) @ Ic, Vce:

180 @ 2mA, 5V

Frequency - Transition:

200MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-92-B1

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

HTSUS:

8541.21.0075

ECCN:

EAR99

# 2SA1127

## Silicon PNP epitaxial planar type

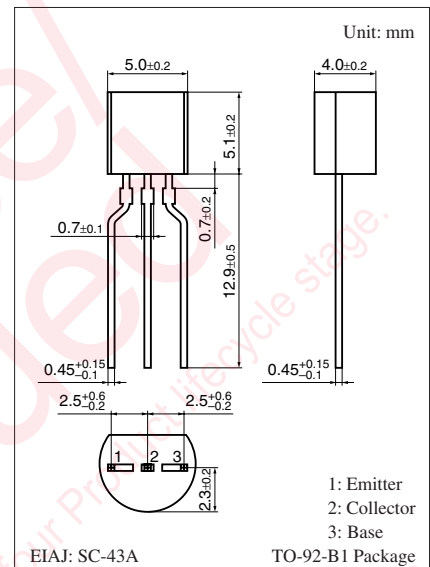
For low-frequency and low-noise amplification  
Complementary to 2SC2634

### ■ Features

- Low noise voltage NV
- High forward current transfer ratio  $h_{FE}$

### ■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	-60	V
Collector-emitter voltage (Base open)	$V_{CEO}$	-55	V
Emitter-base voltage (Collector open)	$V_{EBO}$	-7	V
Collector current	$I_C$	-100	mA
Peak collector current	$I_{CP}$	-200	mA
Collector power dissipation	$P_C$	400	mW
Junction temperature	$T_j$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$



### ■ Electrical Characteristics $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

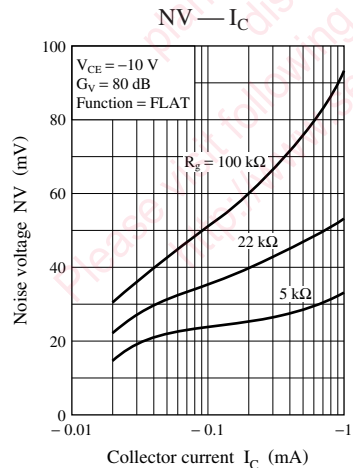
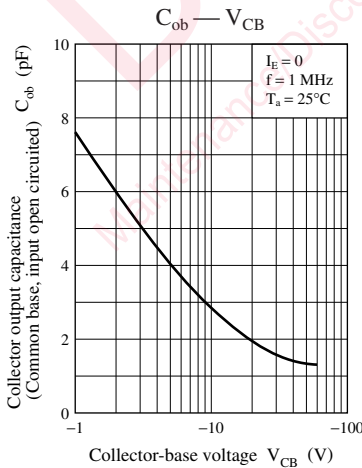
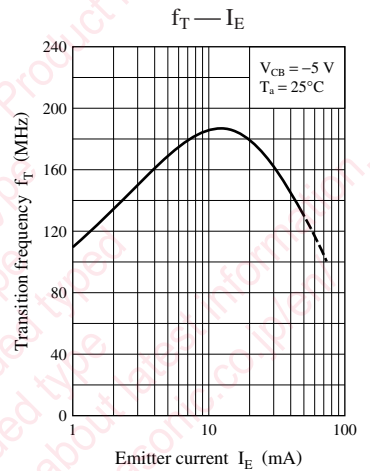
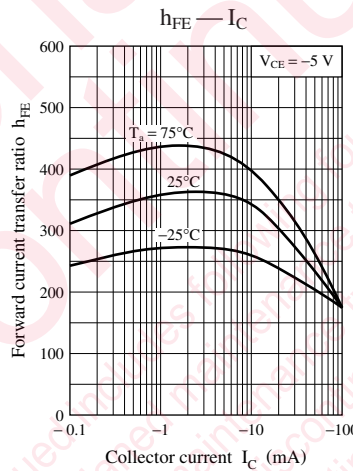
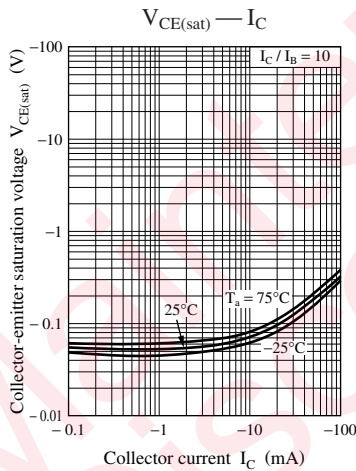
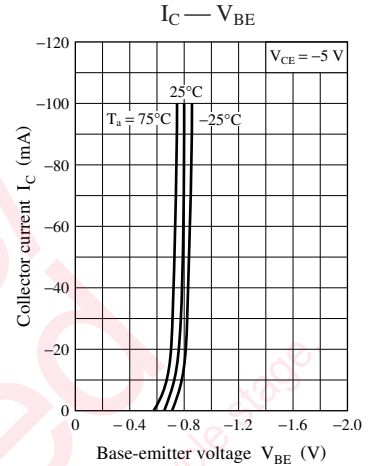
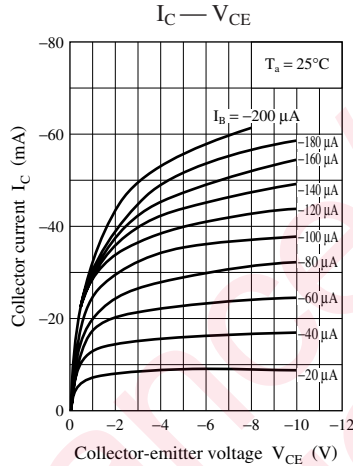
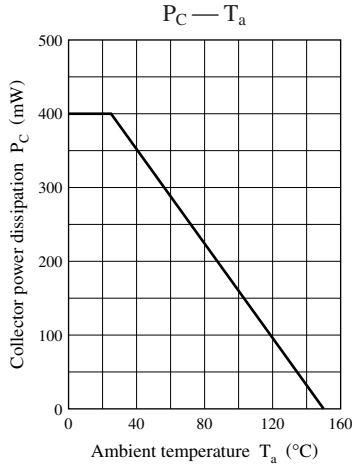
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-base voltage (Emitter open)	$V_{CBO}$	$I_C = -10 \mu\text{A}, I_E = 0$	-60			V
Collector-emitter voltage (Base open)	$V_{CEO}$	$I_C = -1 \text{ mA}, I_B = 0$	-55			V
Emitter-base voltage (Collector open)	$V_{EBO}$	$I_E = -10 \mu\text{A}, I_C = 0$	-7			V
Base-emitter voltage	$V_{BE}$	$V_{CE} = -1 \text{ V}, I_C = -30 \text{ mA}$			-1	V
Collector-base cutoff current (Emitter open)	$I_{CBO}$	$V_{CB} = -10 \text{ V}, I_E = 0$		-1	-100	nA
Collector-emitter cutoff current (Base open)	$I_{CEO}$	$V_{CE} = -10 \text{ V}, I_B = 0$		-0.01	-1.00	$\mu\text{A}$
Forward current transfer ratio *	$h_{FE}$	$V_{CE} = -5 \text{ V}, I_C = -2 \text{ mA}$	180		700	—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = -100 \text{ mA}, I_B = -10 \text{ mA}$			-0.6	V
Transition frequency	$f_T$	$V_{CB} = -5 \text{ V}, I_E = 2 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Noise voltage	NV	$V_{CE} = -10 \text{ V}, I_C = -1 \text{ mA}, G_V = 80 \text{ dB}$ $R_g = 100 \text{ k}\Omega, \text{Function} = \text{FLAT}$			150	mV

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

Rank	R	S	T
$h_{FE}$	180 to 360	260 to 520	360 to 700





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